

Vishay Siliconix

P-Channel 40-V (D-S) MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	R_{DS(on)} (Ω)	I _D (A) ^b		
- 40	0.082 at V _{GS} = - 10 V	- 3.0		
	0.130 at V _{GS} = - 4.5 V	- 2.4		

FEATURES

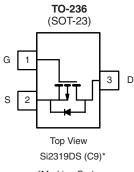
- Halogen-free According to IEC 61249-2-21 Available
- TrenchFET[®] Power MOSFET

APPLICATIONS

Load Switch



COMPLIANT HALOGEN FREE Available



*Marking Code

Ordering Information: Si2319DS-T1-E3 (Lead (Pb)-free) Si2319DS-T1-GE3 (Lead (Pb)-free and Halogen-free)

ABSOLUTE MAXIMUM RATINGS	ſ _A = 25 °C, unle	ss otherwise r	oted			
Parameter		Symbol	5 s	Steady State	Unit	
Drain-Source Voltage		V _{DS}	- 40		V	
Gate-Source Voltage		V _{GS}	± 20			
Continuous Durin Coursent (T. 150 °C)	T _A = 25 °C	I	- 3.0	- 2.3		
Continuous Drain Current (T _J = 150 °C) ^b	T _A = 70 °C	- ^I D	- 2.4	- 1.85		
Pulsed Drain Current ^a		I _{DM}	- 12		A	
Continuous Source Current (Diode Conduction) ^b		۱ _S	- 1.0	- 0.62		
Deven Dissission	T _A = 25 °C	P	1.25	0.75	W	
Power Dissipation ^b	T _A = 70 °C	P _D	0.8	0.48	vv	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C	

THERMAL RESISTANCE RATINGS					
Parameter	Symbol	Typical	Maximum	Unit	
Maximum Junction-to-Ambient ^b	R _{thJA}	75	100		
Maximum Junction-to-Ambient ^c	' 'thJA	120	166	°C/W	
Maximum Junction-to-Foot (Drain)	R _{thJF}	40	50		

Notes:

a. Pulse width limited by maximum junction temperature.

b. Surface mounted on FR4 board, $t \leq 5 \mbox{ s.}$

c. Surface Mounted on FR4 board.

For Spice model information via the worldwide web: www.vishay.com/www/product/spice.htm.

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SPECIFICATIONS T _J = 25 °C, unless otherwise noted							
			Limits				
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 V, I_D = -250 \mu A$	- 40			V	
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = -250 \ \mu A$	- 1		- 3.0	v	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA	
	1	$V_{DS} = -40 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$			- 1		
Zero Gate Voltage Drain Current	IDSS	V_{DS} = - 40 V, V_{GS} = 0 V, T_{J} = 55 °C	- 10		- 10	μΑ	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \leq$ - 5 V, V_{GS} = - 10 V	- 6			А	
Drain-Source On-State Resistance ^a	Б	V _{GS} = - 10 V, I _D = - 3.0 A		0.065	0.082	Ω	
	R _{DS(on)}	$V_{GS} = -4.5 \text{ V}, I_D = -2.4 \text{ A}$		0.100	0.130		
Forward Transconductance ^a	9 _{fs}	$V_{DS} = -5 V, I_{D} = -3.0 A$		7.0		S	
Diode Forward Voltage ^a	V _{SD}	I _S = - 1.25 A, V _{GS} = 0 V		- 0.8	- 1.2	V	
Dynamic ^b							
Total Gate Charge	Qg	N 00 X X 10 X		11.3	17		
Gate-Source Charge	Q _{gs}	V _{DS} = - 20 V, V _{GS} = - 10 V I _D ≅ - 3 A		1.7		nC	
Gate-Drain Charge	Q _{gd}	1D = - 2 X		3.3			
Input Capacitance	C _{iss}			470			
Output Capacitance	C _{oss}	V_{DS} = - 20 V, V_{GS} = 0 V, f = 1 MHz		85		pF	
Reverse Transfer Capacitance	C _{rss}			65		1	
Switching ^c							
Turn-On Time	t _{d(on)}			7	15	- ns	
ium-on time	t _r	V_{DD} = - 20 V, R _L = 20 Ω I _D ≅ - 1.0 A, V _{GEN} = - 4.5 V		15	25		
Turn-Off Time	t _{d(off)}	$R_{\rm g} = 6 \ \Omega$		25	40		
	t _f			25	40		

Notes:

a. Pulse test: PW \leq 300 μs duty cycle \leq 2 %.

b. For design aid only, not subject to production testing.

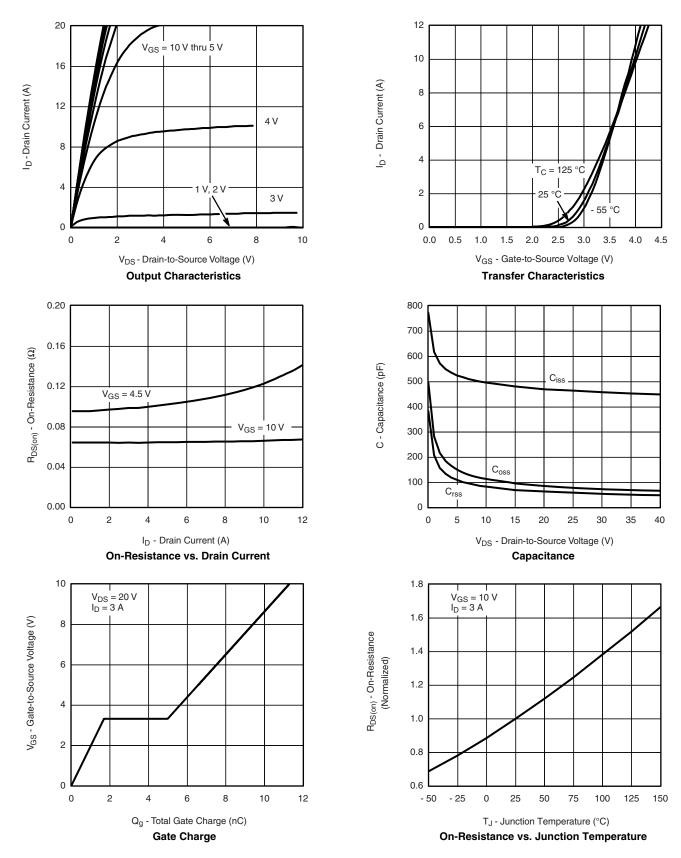
c. Switching time is essentially independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



Si2319DS Vishay Siliconix

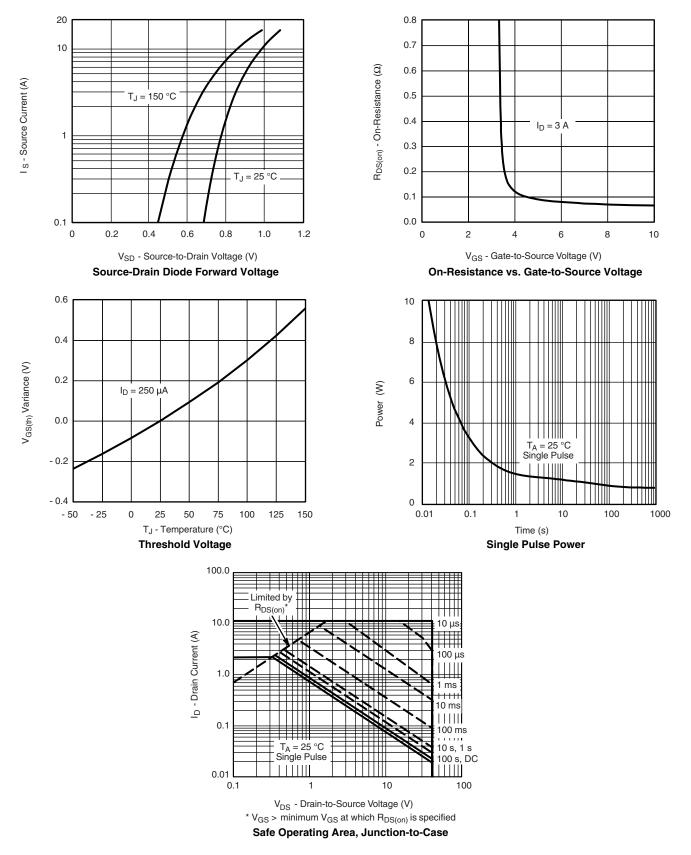
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

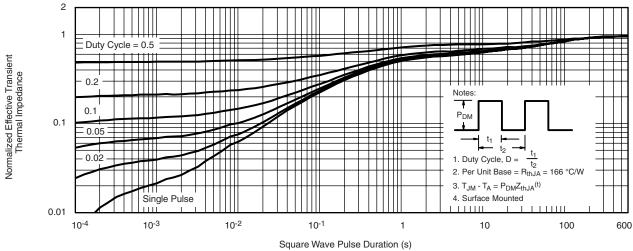




Si2319DS

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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Ambient

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see <u>www.vishay.com/ppg272315</u>.



Package Information

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SOT-23 (TO-236): 3-LEAD







Dim	MILLIN	METERS	INCHES		
	Min	Max	Min	Мах	
Α	0.89	1.12	0.035	0.044	
A ₁	0.01	0.10	0.0004	0.004	
A ₂	0.88	1.02	0.0346	0.040	
b	0.35	0.50	0.014	0.020	
С	0.085	0.18	0.003	0.007	
D	2.80	3.04	0.110	0.120	
E	2.10	2.64	0.083	0.104	
E ₁	1.20	1.40	0.047	0.055	
е	0.95 BSC		0.0374 Ref		
e ₁	1.90 BSC		0.0748 Ref		
L	0.40	0.60	0.016	0.024	
L ₁	0.64 Ref		0.025 Ref		
S	0.50 Ref		0.020 Ref		
q	3°	8°	3°	8°	



Mounting LITTLE FOOT[®] SOT-23 Power MOSFETs

Wharton McDaniel

Surface-mounted LITTLE FOOT power MOSFETs use integrated circuit and small-signal packages which have been been modified to provide the heat transfer capabilities required by power devices. Leadframe materials and design, molding compounds, and die attach materials have been changed, while the footprint of the packages remains the same.

See Application Note 826, *Recommended Minimum Pad Patterns With Outline Drawing Access for Vishay Siliconix MOSFETs*, (http://www.vishay.com/doc?72286), for the basis of the pad design for a LITTLE FOOT SOT-23 power MOSFET footprint . In converting this footprint to the pad set for a power device, designers must make two connections: an electrical connection and a thermal connection, to draw heat away from the package.

The electrical connections for the SOT-23 are very simple. Pin 1 is the gate, pin 2 is the source, and pin 3 is the drain. As in the other LITTLE FOOT packages, the drain pin serves the additional function of providing the thermal connection from the package to the PC board. The total cross section of a copper trace connected to the drain may be adequate to carry the current required for the application, but it may be inadequate thermally. Also, heat spreads in a circular fashion from the heat source. In this case the drain pin is the heat source when looking at heat spread on the PC board.

Figure 1 shows the footprint with copper spreading for the SOT-23 package. This pattern shows the starting point for utilizing the board area available for the heat spreading copper. To create this pattern, a plane of copper overlies the drain pin and provides planar copper to draw heat from the drain lead and start the process of spreading the heat so it can be dissipated into the

ambient air. This pattern uses all the available area underneath the body for this purpose.



FIGURE 1. Footprint With Copper Spreading

Since surface-mounted packages are small, and reflow soldering is the most common way in which these are affixed to the PC board, "thermal" connections from the planar copper to the pads have not been used. Even if additional planar copper area is used, there should be no problems in the soldering process. The actual solder connections are defined by the solder mask openings. By combining the basic footprint with the copper plane on the drain pins, the solder mask generation occurs automatically.

A final item to keep in mind is the width of the power traces. The absolute minimum power trace width must be determined by the amount of current it has to carry. For thermal reasons, this minimum width should be at least 0.020 inches. The use of wide traces connected to the drain plane provides a low-impedance path for heat to move away from the device.



Application Note 826

Vishay Siliconix

RECOMMENDED MINIMUM PADS FOR SOT-23



Recommended Minimum Pads Dimensions in Inches/(mm)

Return to Index



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